

View Online at <https://aerobasegroup.com/nsn/5961-01-036-5097>

**Inclosure Material:**

Glass all semiconductor device diode

**Overall Length:**

0.140 inches all semiconductor device diode and 0.160 inches all semiconductor device diode

**Terminal Length:**

1.000 inches all semiconductor device diode and 1.500 inches all semiconductor device diode

**Overall Diameter:**

0.056 inches all semiconductor device diode and 0.075 inches all semiconductor device diode

**Internal Configuration:**

Junction contact all semiconductor device diode

**Internal Junction Configuration:**

Pn all semiconductor device diode

**Component Function Relationship:**

Matched

**Component Name And Quantity:**

8 semiconductor device diode

**Mounting Method:**

Terminal all semiconductor device diode

**Semiconductor Material:**

Silicon all semiconductor device diode

**Voltage Rating In Volts Per Characteristic:**

100.0 breakdown voltage, dc all semiconductor device diode and 75.0 working peak reverse voltage all semiconductor device diode

**Current Rating Per Characteristic:**

200.00 milliamperes forward current, average absolute all semiconductor device diode and 1.00 amperes forward current, average preset all semiconductor device diode

**Maximum Operating Temperature Per Measurement Point:**

200.0 degrees celsius junction all semiconductor device diode

**Special Features:**

Forward voltages at 100 microamperes matched w/in 50 millivolts.

**Terminal Type And Quantity:**

2 uninsulated wire lead all semiconductor device diode

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

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